Nch 80V 225A Power MOSFET

V _{DSS}	80V
R _{DS(on)} (Max.)	2.20mΩ
I _D	±225A
P _D	189W

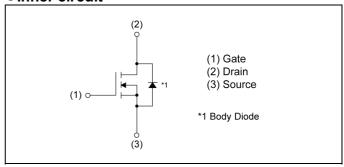
● Outline



Features

- 1) Low on resistance
- 2) High power mold package (TO220AB)
- 3) Pb-free plating; RoHS compliant
- 4) Halogen Free
- 5) 100% Rg and UIS tested

●Inner circuit



Application

Switching

Motor drives

DC/DC converter

Packaging specifications

	Packing	Tube
Turno	Quantity (pcs)	1000
Type	Taping code	C16
	Marking	RX3N10BBH

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

Parar	Symbol	Value	Unit	
Drain - Source voltage	V_{DSS}	80	V	
Continuous drain current	Silicon limit (V _{GS} =10V)	I _D *1	±225	Α
Continuous drain current	$T_c = 25^{\circ}C (V_{GS} = 10V)$	I _D *2	±105	Α
Pulsed drain current	I _{DP} *3	±900	Α	
Gate - Source voltage	V_{GSS}	±20	V	
Avalanche current, single pu	l _{AS} *4	62	Α	
Avalanche energy, single pu	E _{AS} *4	312	mJ	
Power dissipation	P _D *2	189	W	
Junction temperature	T _j	150	°C	
Operating junction and stora	T _{stg}	-55 to +150	°C	

●Thermal resistance

Parameter	Symbol	Values			Lleit
		Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R _{thJC} *2	-	1	0.66	°C/W

● Electrical characteristics (T_a = 25°C)

Darameter	Symbol	Conditions	Values			Unit
Parameter Symbol Conditions		Conditions	Min.	Тур.	Max.	Offic
Drain - Source breakdown voltage	V _{(BR)DSS}	$V_{GS} = 0V, I_D = 1mA$	80	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}}$	I _D = 1mA referenced to 25°C	-	58	-	mV/°C
Zero gate voltage drain current	I _{DSS}	V _{DS} = 80V, V _{GS} = 0V	-	-	5	μA
Gate - Source leakage current	I _{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$	1	-	±500	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = 1mA$	2.0	-	4.0	V
Gate threshold voltage temperature coefficient	$\frac{\DeltaV_{GS(th)}}{\DeltaT_j}$	I _D = 1mA referenced to 25°C	-	-5.0	-	mV/°C
Static drain - source	D *5	V _{GS} = 10V, I _D = 90A	-	1.76	2.20	m0
on - state resistance	R _{DS(on)} *5	V _{GS} = 6V, I _D = 50A	-	2.10	2.90	mΩ
Gate resistance	R _G -		ı	8.0	-	Ω
Forward Transfer Admittance	Y _{fs} *5	$V_{DS} = 5V, I_{D} = 50A$	55	-	-	S

^{*1} Limited by silicon chip capability.

^{*2} T_c =25°C, Limited only by maximum temperature allowed.

^{*3} Pw \leq 10µs, Duty cycle \leq 1%

^{*4} L \simeq 0.1mH, V_{DD} = 40V, R_G = 25 Ω , Starting T_j = 25 $^{\circ}$ C Fig.3-1,3-2

^{*5} Pulsed

● Electrical characteristics (T_a = 25°C)

Davanastan	Cumbal	Conditions		Lleit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C _{iss}	V _{GS} = 0V	-	11800	-	
Output capacitance	C _{oss}	V _{DS} = 40V	-	2560	-	pF
Reverse transfer capacitance	C _{rss}	f = 1MHz	-	95	-	
Turn - on delay time	t _{d(on)} *5	V _{DD} ≈ 40V,V _{GS} = 10V	-	58	-	
Rise time	t _r *5	I _D = 50A	-	66	-	
Turn - off delay time	t _{d(off)} *5	$R_L \simeq 0.8\Omega$	-	250	-	ns
Fall time	t _f *5	$R_G = 10\Omega$	-	340	-	

● Gate charge characteristics (T_a = 25°C)

Doromotor	Cymahal	mbol Conditions		Values			l lait
Parameter	Symbol	Conditi	Oris	Min.	Тур.	Max.	Unit
Total gate charge	O *5		V _{GS} = 10V	-	185	-	
Total gate charge	Q_g^{*5}	V _{DD} ≈ 40V		-	120	-	~C
Gate - Source charge	Q _{gs} *5	I _D = 50A	V _{GS} = 6V	-	39	-	nC
Gate - Drain charge	Q _{gd} *5			-	38	-	

●Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

Downwater	Cymahal	Conditions		Samuel Constitutions			Values					Linit
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit						
Continuous forward current	I _S *2	T _a = 25°C	-	-	105	Α						
Pulse forward current	I _{SP} *3	1 _a - 25 C	-	-	900	Α						
Forward voltage	V _{SD} *5	V _{GS} = 0V, I _S = 90A	-	-	1.5	V						
Reverse recovery time	t _{rr} *5	I _S = 50A, V _{GS} =0V	-	92	-	ns						
Reverse recovery charge	Q _{rr} *5	di/dt = 100A/µs	-	220	-	nC						

Power Dissipation: P_D/P_{Dmax}. [%]

• Electrical characteristic curves

Fig.1 Power Dissipation Derating Curve

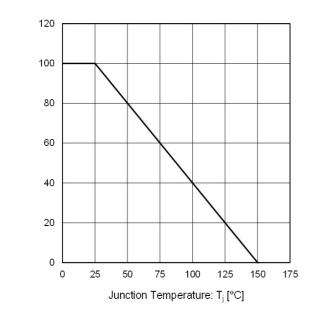
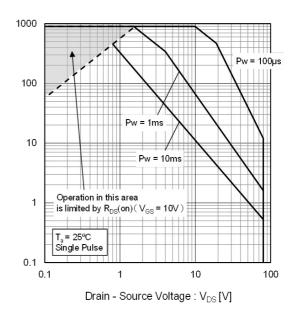


Fig.2 Maximum Safe Operating Area



Drain Current : I_D [A]

Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

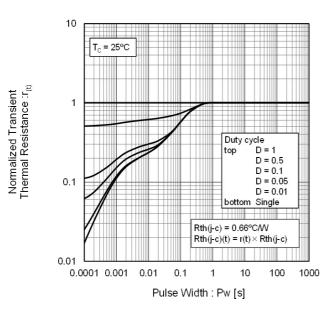
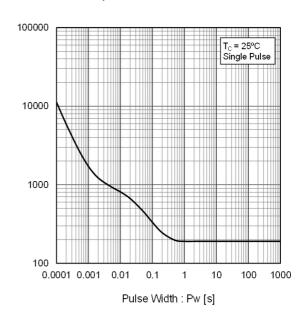


Fig.4 Single Pulse Maximum Power Dissipation



Peak Transient Power: P[W]

Drain Current : I_D [A]

Normalized Breakdown Voltage : $V_{(BR)DSS}$

• Electrical characteristic curves

Fig.5 Typical Output Characteristics(I)

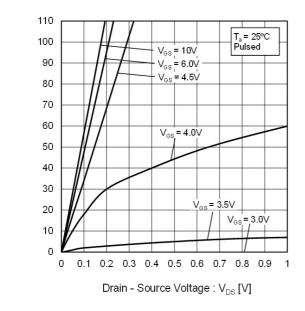


Fig.6 Typical Output Characteristics(II)

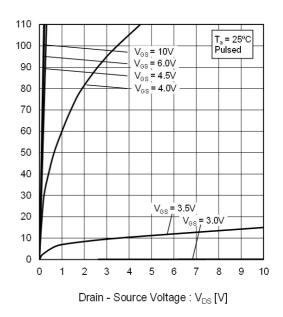


Fig.7 Normalized Breakdown Voltage vs. Junction Temperature

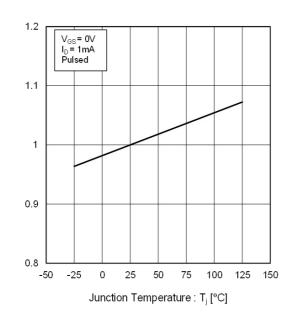
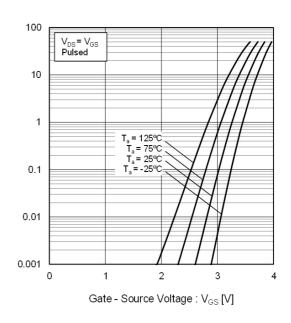


Fig.8 Typical Transfer Characteristics



Drain Current : I_D [A]

Drain Current : I_D [A]

Gate Threshold Voltage : V_{GS(th)} [V]

• Electrical characteristic curves

Fig.9 Gate Threshold Voltage vs.
Junction Temperature

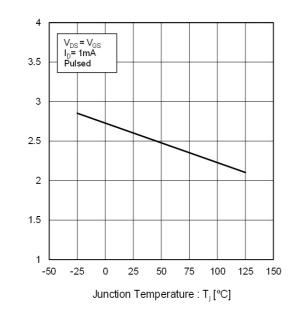


Fig.10 Forward Transfer Admittance vs.
Drain Current

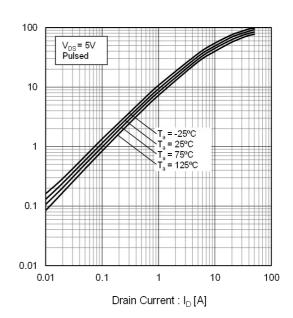


Fig.11 Drain Current Derating Curve

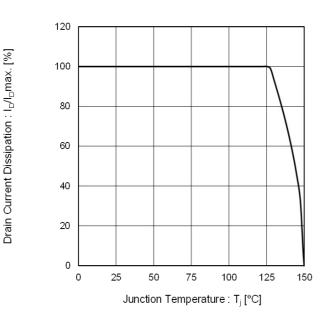
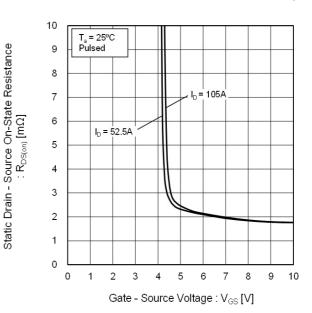


Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



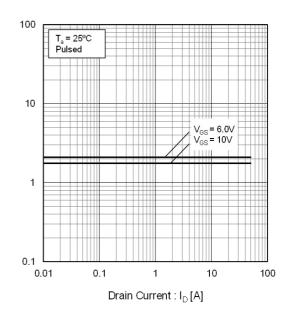
Forward Transfer Admittance : Y_{fs} [S]

• Electrical characteristic curves

Fig.13 Static Drain - Source On - State Resistance vs. Junction Temperature

5 V_{GS}= 10V Pulsed Static Drain - Source On-State Resistance 4 : R_{DS(on)} [mΩ] 3 2 $I_D = 50A$ 1 0 -50 -25 0 50 75 100 125 150 Junction Temperature : T_i [°C]

Fig.14 Static Drain - Source On - State
Resistance vs. Drain Current (I)



Static Drain - Source On-State Resistance : $R_{\mathrm{DS}(on)}\left[m\Omega\right]$

Static Drain - Source On-State Resistance : $R_{\mathrm{DS}(\text{on})}\left[m\Omega\right]$

Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)

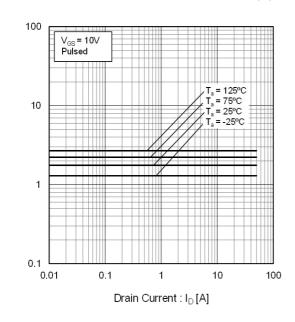
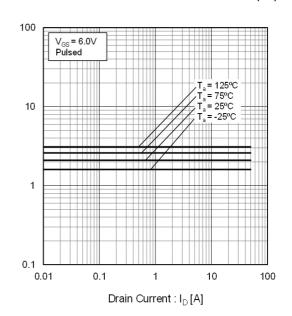


Fig.16 Static Drain - Source On - State Resistance vs. Drain Current (III)



Static Drain - Source On-State Resistance

 $:R_{DS(on)}[m\Omega]$

• Electrical characteristic curves

Fig.17 Typical Capacitances vs.

Drain - Source Voltage

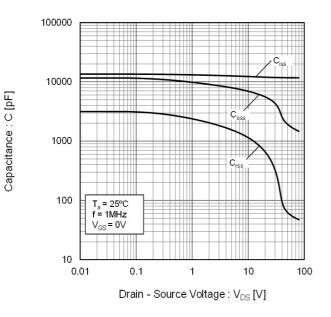
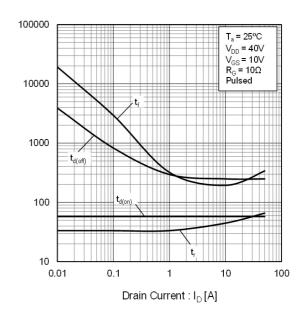


Fig.18 Switching Characteristics



Switching Time : t [ns]

Fig.19 Typical Gate Charge

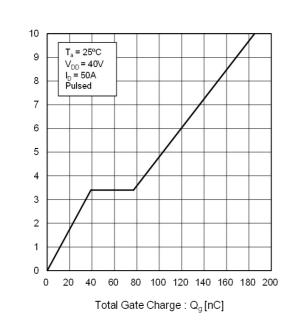
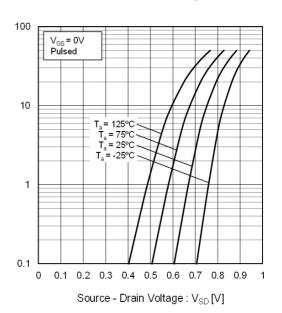


Fig.20 Source Current vs.

Source Drain Voltage



Gate - Source Voltage : V_{GS} [V]

Source Current : I_s [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

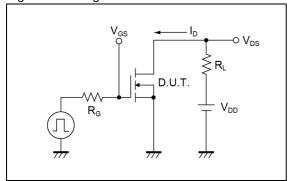


Fig.1-2 Switching Waveforms

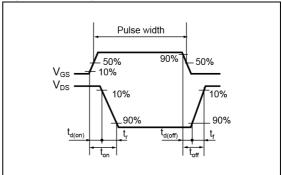


Fig.2-1 Gate Charge Measurement Circuit

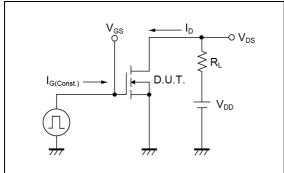


Fig.2-2 Gate Charge Waveform

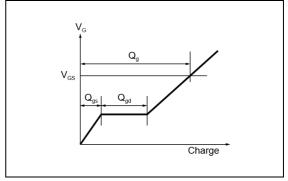


Fig.3-1 Avalanche Measurement Circuit

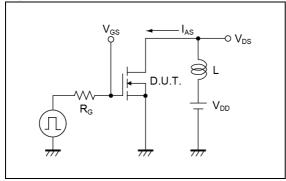
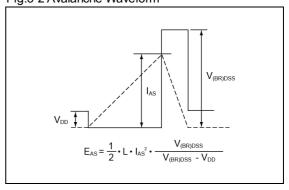
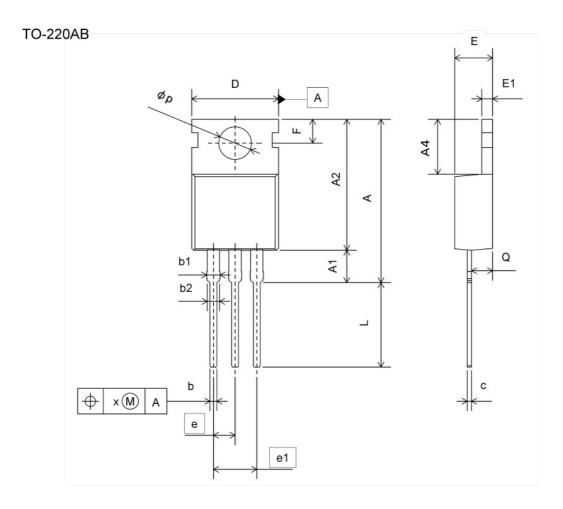


Fig.3-2 Avalanche Waveform



Dimensions



DIM	MILIME	TERS	INCI	HES
DIM	MIN	MAX	MIN	MAX
Α	18.30	20.00	0.720	0.787
A1	3.60	4.00	0.142	0.157
A2	14.70	16.00	0.579	0.630
A4	6.30	6.60	0.248	0.260
b	0.65	0.95	0.026	0.037
b1	1.20	1.75	0.047	0.069
b2	1.20	1.70	0.047	0.067
С	0.35	0.65	0.014	0.026
D	9.96	10.36	0.392	0.408
E	4.24	4.64	0.167	0.183
E1	1.14	1.40	0.045	0.055
е	2.	54	0.1	00
e1	5.	08	0.2	200
F	2.60	3.00	0.102	0.118
L	9.47	10.37	0.373	0.408
φp	3.69	3.99	0.145	0.157
Q	2.30	2.70	0.091	0.106
Х	20	0.38	<u>~</u>	0.015

Dimension in mm/inches



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JÁPAN	USA	EU	CHINA
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CLASSIV	CLASSⅢ	CLASSⅢ	CLASSⅢ

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 - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
 - [f] Sealing or coating our Products with resin or other coating materials
 - [g] Use of our Products without cleaning residue of flux (Exclude cases where no-clean type fluxes is used. However, recommend sufficiently about the residue.); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
 - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse, is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

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- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

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This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

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 - [a] the Products are exposed to sea winds or corrosive gases, including Cl₂, H₂S, NH₃, SO₂, and NO₂
 - [b] the temperature or humidity exceeds those recommended by ROHM
 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
- Even under ROHM recommended storage condition, solderability of products out of recommended storage time period
 may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is
 exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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